

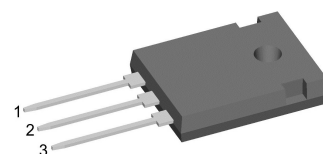
Schottky Diode

$$\begin{aligned} V_{RRM} &= 60 \text{ V} \\ I_{FAV} &= 2 \times 20 \text{ A} \\ V_F &= 0.46 \text{ V} \end{aligned}$$

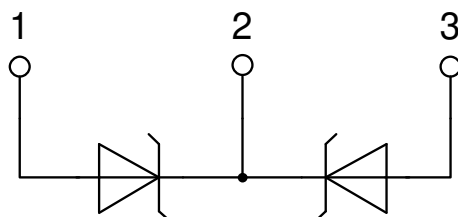
High Performance Schottky Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DSSK40-006B



Backside: cathode



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

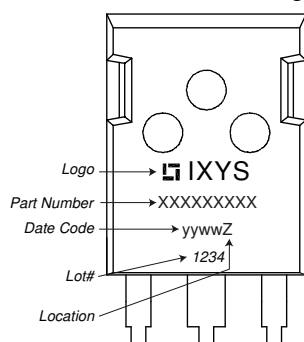
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Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocking voltage	T _{VJ} = 25°C				60	V
V _{RRM}	max. repetitive reverse blocking voltage	T _{VJ} = 25°C				60	V
I _R	reverse current, drain current	V _R = 60 V	T _{VJ} = 25°C			20	mA
		V _R = 60 V	T _{VJ} = 100°C			100	mA
V _F	forward voltage drop	I _F = 20 A	T _{VJ} = 25°C			0.50	V
		I _F = 40 A				0.67	V
		I _F = 20 A	T _{VJ} = 125°C			0.46	V
		I _F = 40 A				0.62	V
I _{FAV}	average forward current	T _C = 135°C rectangular d = 0.5	T _{VJ} = 150°C			20	A
V _{F0}	threshold voltage	} for power loss calculation only				0.31	V
r _F	slope resistance					6.9	mΩ
R _{thJC}	thermal resistance junction to case					1.1	K/W
R _{thCH}	thermal resistance case to heatsink				0.25		K/W
P _{tot}	total power dissipation	T _C = 25°C				115	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; V _R = 0 V		T _{VJ} = 45°C		500	A
C _J	junction capacitance	V _R = 12 V f = 1 MHz		T _{VJ} = 25°C		888	pF

Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			70	A
T_{VJ}	virtual junction temperature		-55		150	°C
T_{op}	operation temperature		-55		125	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

Product Marking



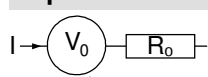
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSSK40-006B	DSSK40-006B	Tube	30	479136

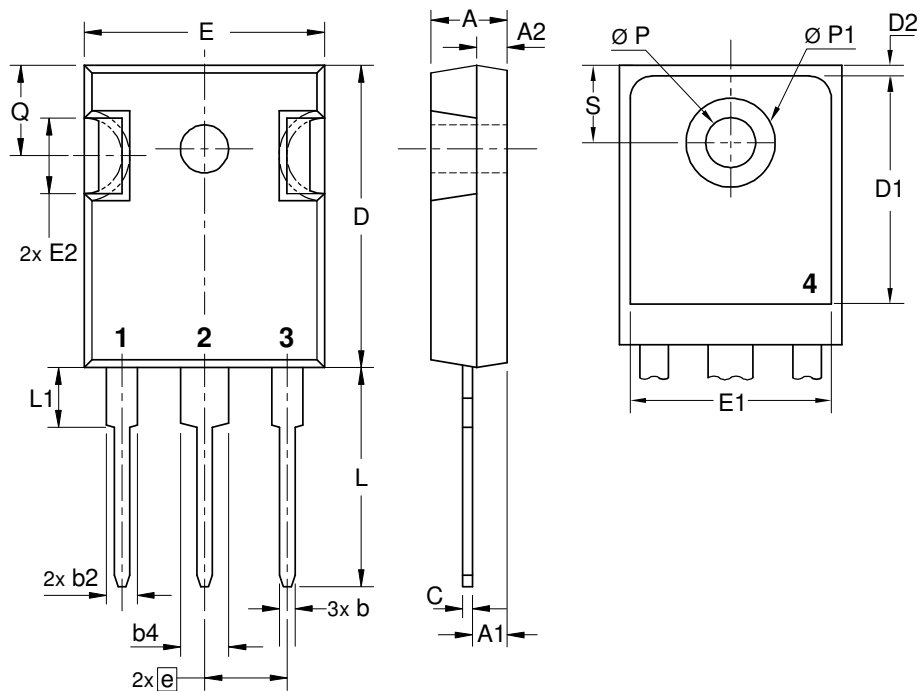
Similar Part	Package	Voltage class
DSB60C60HB	TO-247AD (3)	60
DSB60C60PB	TO-220AB (3)	60

Equivalent Circuits for Simulation

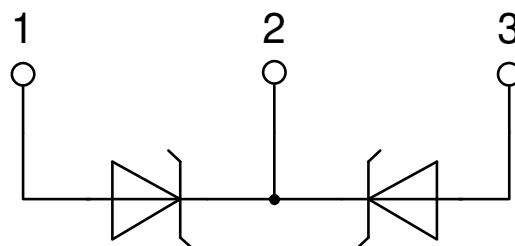
^{*} on die level

$T_{VJ} = 150^{\circ}\text{C}$

		Schottky	
$V_{0\text{ max}}$	threshold voltage	0.31	V
$R_{0\text{ max}}$	slope resistance [*]	4.4	mΩ

Outlines TO-247


Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215	BSC	5.46	BSC
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242	BSC	6.14	BSC
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39



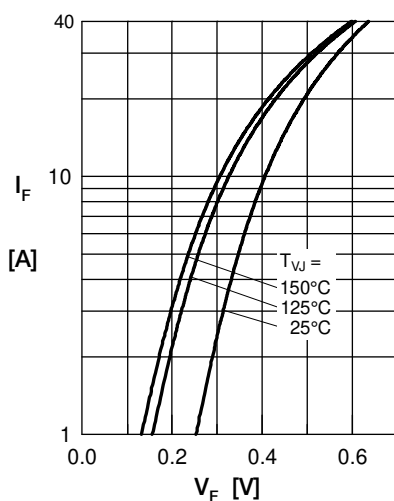
Schottky


Fig. 1 Max: forward voltage drop characteristics

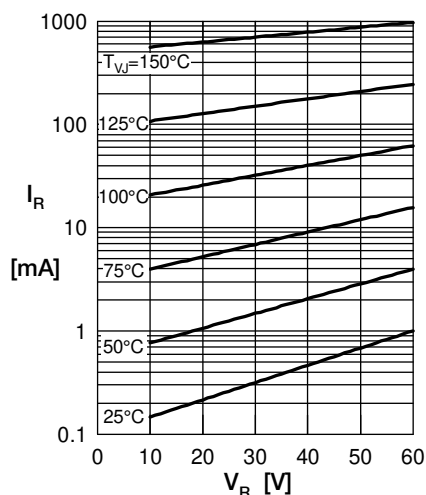
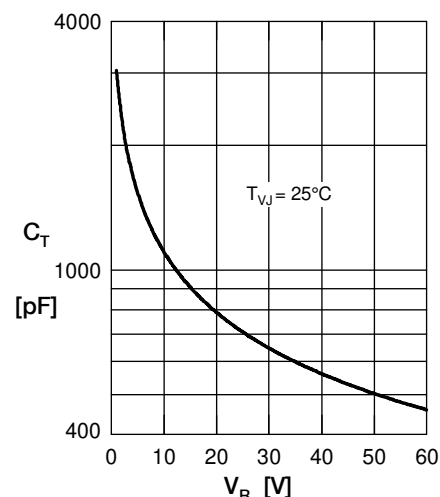
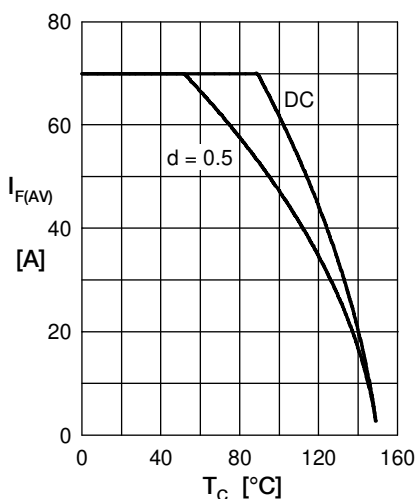
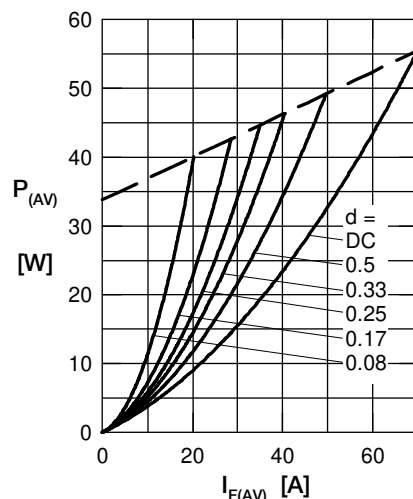

 Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

 Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

 Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp: T_C


Fig. 5 Forward power loss characteristics

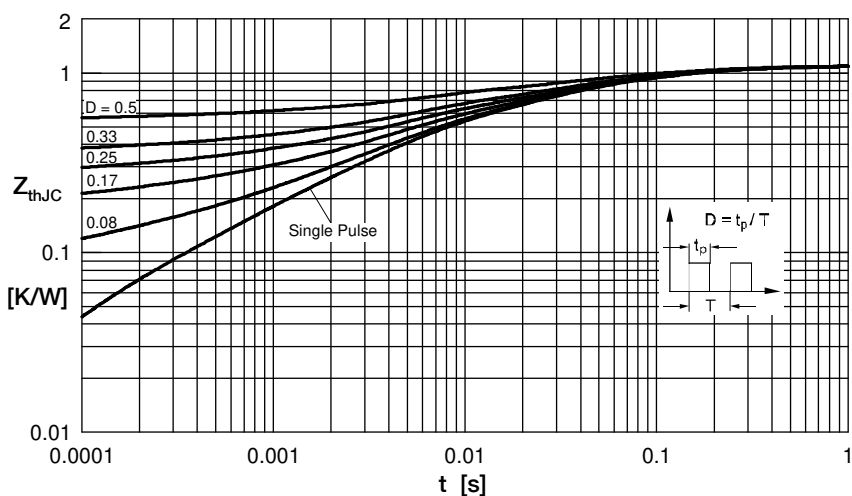


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode